

MPS5179

Preferred Device

High Frequency Transistor

NPN Silicon

Features

- Pb-Free Packages are Available*

MAXIMUM RATINGS

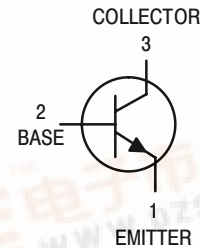
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	12	Vdc
Collector-Base Voltage	V_{CBO}	20	Vdc
Emitter-Base Voltage	V_{EBO}	2.5	Vdc
Collector Current - Continuous	I_C	50	mA _{dc}
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	200 1.14	W mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	300 1.71	W mW/ $^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

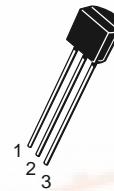


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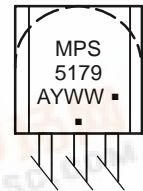
<http://onsemi.com>



MARKING DIAGRAM



TO-92
CASE 29-11
STYLE 1



MPS5179 = Device Code
A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MPS5179	TO-92	5000 Units/Box
MPS5179G	TO-92 (Pb-Free)	5000 Units/Box
MPS5179RLRA	TO-92	2000/Tape & Reel
MPS5179RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel
MPS5179RLRP	TO-92	2000/Tape & Ammo
MPS5179RLRPG	TO-92 (Pb-Free)	2000/Tape & Ammo

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



MPS5179

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

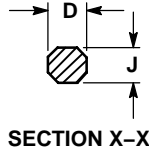
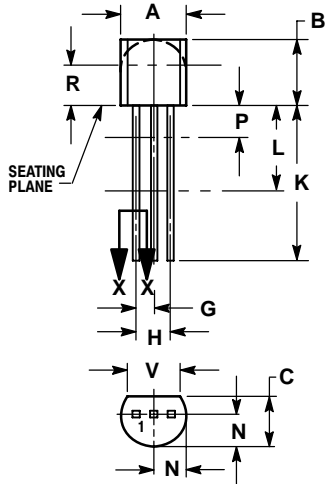
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage ($I_C = 3.0\text{ mAdc}$, $I_B = 0$)	$V_{CEO(sus)}$	12	–	Vdc
Collector–Base Breakdown Voltage ($I_C = 0.001\text{ mAdc}$, $I_E = 0$)	$V_{(BR)CBO}$	20	–	Vdc
Emitter–Base Breakdown Voltage ($I_E = 0.01\text{ mAdc}$, $I_C = 0$)	$V_{(BR)EBO}$	2.5	–	Vdc
Collector Cutoff Current ($V_{CB} = 15\text{ Vdc}$, $I_E = 0$) ($V_{CB} = 15\text{ Vdc}$, $I_E = 0$, $T_A = 150^\circ\text{C}$)	I_{CBO}	– –	0.02 1.0	μAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 3.0\text{ mAdc}$, $V_{CE} = 1.0\text{ Vdc}$)	h_{FE}	25	250	–
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mAdc}$, $I_B = 1.0\text{ mAdc}$)	$V_{CE(sat)}$	–	0.4	Vdc
Base–Emitter Saturation Voltage ($I_C = 10\text{ mAdc}$, $I_B = 1.0\text{ mAdc}$)	$V_{BE(sat)}$	–	1.0	Vdc
SMALL–SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product (Note 1) ($I_C = 5.0\text{ mAdc}$, $V_{CE} = 6.0\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	900	2000	MHz
Collector–Base Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 0.1\text{ to }1.0\text{ MHz}$)	C_{cb}	–	1.0	pF
Small Signal Current Gain ($I_C = 2.0\text{ mAdc}$, $V_{CE} = 6.0\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	25	300	–

1. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

MPS5179

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AL



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 1:

1. EMITTER
2. BASE
3. COLLECTOR

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